

# PRELIMINARY

August 1996

# Portable Battery Drive/Torque Controller for N-Channel MOSFETs in Motor Control Systems

### Features

- MOSFET Driver and DC Motor Controller
- Torque Control and Overload Protection
- Battery Power Supply ..... +5V to +15V
- BiMOS IC with Low Operating Current
  - Maximum Supply Current .....1.5mA
- Maximum Input Leakage Currents  $\dots \dots 1.5 \mu A$
- 500µA Maximum Supply Current
- 1µA Maximum Input Leakage Currents
- Typical Oscillator Frequency ......5kHz
- Power-On-Reset Control
- 10mA Drive Capability for Gate Output
- Operating Temperature . . . . . . 40<sup>o</sup>C to +85<sup>o</sup>C Range

### Applications

- Portable Battery Operated Electric Drills
- Controller for Small DC Electric Motors
- Torque/Drive Controller for Inductive Loads
- Intelligent MOSFET Drive

### **Ordering Information**

PART NUMBER	TEMP. RANGE ( <sup>o</sup> C)	PACKAGE	PKG. NO.
HIP9021IB	-40 to +85	8 Ld SOIC	M8.15

### Pinout

# DRAIN 1 8 V<sub>DD</sub> TRIGGER 2 7 GATE GND 3 6 DELAY OSC 4 5 TORQUE

HIP9021IB (SOIC) TOP VIEW

### Description

The HIP9021IB is a dedicated Power MOSFET driver which drives a DC motor. As a system, motor speed is controlled while controlling torque. The primary application is drive control for portable drills while providing overload protection.

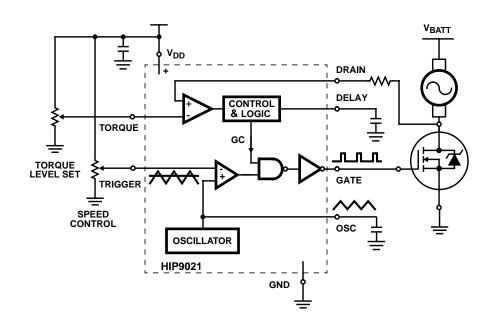
HIP9021

The main function of the HIP9021IB is to produce a pulse width modulated square wave signal which drives the gate of an N-Channel Power MOSFET. The duty-cycle is determined by the setting of an external potentiometer at the TRIGGER (speed control) input. As the TRIGGER voltage level is decreased the duty-cycle of the square wave and the speed of the motor is increased.

The torque of the motor is limited by the voltage level sensed at the drain of the external Power MOSFET. When the current reaches an adjustable limit set at the TORQUE input, the drive of the Power MOSFET is disabled.

The system control components include 2 adjustable potentiometer controls and 2 capacitors for the operating frequency and torque delay control. A fixed or battery supply voltage in the range of 5V to 15V may be used.

The HIP9021IB is provided in a small outline plastic package for a compact surface mount to a ceramic substrate. The surface mount assembly can be fit directly into the trigger of a portable electric drill. Block Diagram



### **Absolute Maximum Ratings**

Supply Voltage+16V
Input Voltage
Maximum Current, I <sub>DD</sub> 50mA
Maximum Transient Reverse Current, I <sub>R</sub> (10s)50mA

### **Operating Conditions**

Typical Power Supply Voltage7.5V	
Operating Voltage Range +5V to +15V	
Operating Temperature Range40°C to 150°C	
Typical Oscillator Frequency 5kHz	

#### **Thermal Information**

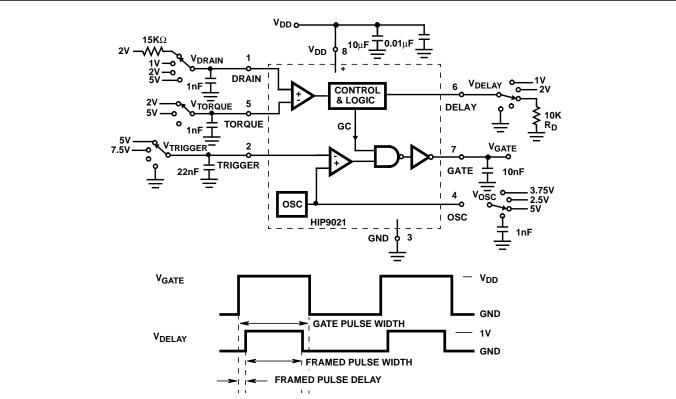
Thermal Resistance (Typical, Note 1)	$\theta_{JA}$ ( <sup>o</sup> C/W)
SOIC Package	175
Maximum Storage Temperature Range65	<sup>o</sup> C to 150 <sup>o</sup> C
Maximum Junction Temperature	150 <sup>0</sup> C
Maximum Lead Temperature (Soldering 10s)	300 <sup>0</sup> C
(Lead Tips Only)	

CAUTION: Stresses above those listed in "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress only rating and operation
of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied.

PARAMETER	SYMBOL	TEST CONDITIONS	MIN	ТҮР	MAX	UNITS
DC Supply Current	I <sub>DD</sub>		0.1	1.2	3.1	mA
OSC Source Current	+losc		19	25	32	μA
OSC Sink Current	-losc		-32	-25	-19	μA
OSC Threshold Voltage	V <sub>OSC(TH)</sub>		4.75	4.95	5.25	V
OSC Trigger Voltage	V <sub>OSC(TR)</sub>		2.30	2.45	2.65	V
TRIGGER Input Leak Current	ITRIGGER		-	0.02	1.5	μA
TORQUE Input Leak Current	ITORQUE		-	0.02	1.5	μA
DELAY Current at 1V	I <sub>DELAY1</sub>		1.5	3.4	6	μA
DELAY Current at 2V	I <sub>DELAY2</sub>		1	32	50	mA
DELAY Threshold Voltage	V <sub>DELAY(TH)</sub>		1.8	1.9	2	V
DRAIN Input Resistance	R <sub>DRAIN</sub>		150	260	350	kΩ
DRAIN Current	I <sub>DRAIN</sub>		1	1.7	4.6	mA
GATE Output Source Current	I <sub>GATE</sub>		10	18	-	mA
GATE Output Voltage	V <sub>GATE</sub>		6.5	7.4	-	V
GATE Output Slew Rate	V <sub>GATE(S/R)</sub>	Measured in Typical Application Circuit, Duty Cycle = 50%, See Figure 2	-	10	-	V/µs
DELAY Output Framed Pulse Duty Cycle	FP/DC	Gate Duty Cycle = 50%; VTORQUE = GND; VDRAIN = VGATE;	-	44	-	%
DELAY Output Framed Pulse De- lay, $V_{GATE}$ to $V_{DELAY}$	FP/DLY	DELAY =10k $\Omega$ to GND, Refer to Figure 1 for the Test circuit and Timing Diagram of the DELAY Output Pulse Frame.	-	3	-	%
Typical Oscillator Frequency	fosc	T <sub>A</sub> = 25 <sup>o</sup> C	-	5	-	kHz
		$T_A = -40^{\circ}C$	-	7.2	-	kHz
		T <sub>A</sub> = 85 <sup>o</sup> C	-	3.6	-	kHz

NOTES:

1.  $\theta_{JA}$  is measured with the component mounted on an evaluation PC board in free air.



NOTE: The timing diagrams relate to the delay output framed pulse and show the time duration of the delay pulse "framed" inside of the gate pulse. The framed pulse duty cycle and delay, in percent, are measured in reference to the gate pulse which is set at 50% duty cycle. The Delay output framed pulse delay is one-half of the difference of the gate pulse width minus delay output framed pulse width.

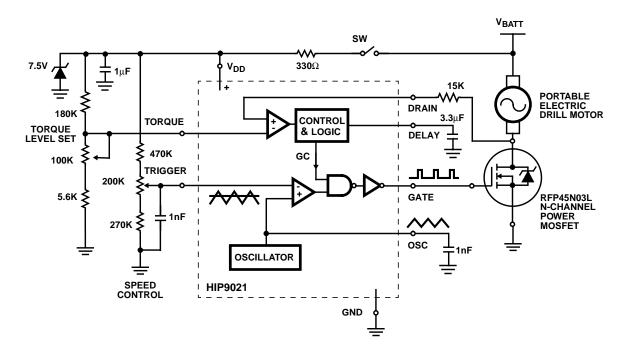
FIGURE 1. ELECTRICAL CHARACTERISTICS TEST CIRCUIT FOR SIGNAL FUNCTIONS OF THE HIP9021

SYMBOL	DRAIN	TRIGGER	OSC	TORQUE	DELAY	GATE	MEASURE
I <sub>DD</sub>	$15 \text{K}\Omega$ to $2 \text{V}$	GND	3.75V	2V	Open	Open	I <sub>DD</sub> Current Into V <sub>DD</sub> Pin
+losc	15KΩ to 2V	GND	2.5V	2V	Open	Open	Source Current From OSC Pin
-losc	$15 \text{K}\Omega$ to $2 \text{V}$	GND	5V	2V	Open	Open	Sink Current Into OSC Pin
V <sub>OSC(TH)</sub>	1V	Open	1nF	2V	Open	Open	Positive Peak OSC Voltage
VOSC(TG)	1V	Open	1nF	2V	Open	Open	Negative Peak OSC Voltage
ITRIGGER	$15 \text{K}\Omega$ to $2 \text{V}$	5V	5V	2V	Open	Open	TRIGGER Leakage Current
ITORQUE	$15 \text{K}\Omega$ to $2 \text{V}$	Open	5V	5V	Open	Open	TORQUE Leakage Current
IDELAY1	$15 \text{K}\Omega$ to $2 \text{V}$	7.5V	1nF	Open	1V	Open	Current to DELAY Pin
IDELAY2	$15 \text{K}\Omega$ to $2 \text{V}$	7.5V	1nF	Open	2V	Open	Current to DELAY Pin
V <sub>DELAY</sub> (TH)	1V	Ramp Up	1nF	2V	GND	Read V <sub>GATE</sub>	Measure V <sub>TRIGGER</sub> When V <sub>GATE</sub> Less Than 0.5V
R <sub>DRAIN</sub>	5V	GND	1nF	2V	GND	Open	DRAIN Current; Calculate R <sub>DRAIN</sub> = 5V/I <sub>DRAIN</sub>
IDRAIN	1V	7.5V	5V	2V	Open	Open	DRAIN Current
V <sub>GATE</sub>	5V	GND	1nF	2V	Open	Open	Measure V <sub>GATE</sub> = V <sub>OUT</sub>
I <sub>GATE</sub>	2V	GND	1nF	2V	GND	Set to V <sub>OUT</sub> -0.5V	Measure I <sub>GATE</sub> Source Current with $V_{GATE} = V_{OUT}$ -0.5V
VGATE(S/R)	Refe	r to Figure 2 Ap	plication Circ	uit, 50% GATI	Output Duty	, Cycle	GATE Output Slew Rate
FP/DC							Reference Figure 1 Waveforms
FP/DLY							Reference Figure 1 Waveforms
fosc	1V	V <sub>OSC(TH)</sub> - -1V	1nF	2V	GND	25KΩ Load	GATE Output Timing

#### TABLE 1. SWITCH POSITIONS OF FIGURE 1 FOR ELECTRICAL CHARACTERISTIC TESTING

## **Pin Descriptions**

NAME	NUMBER	DESCRIPTION
DRAIN	1	The input to the DRAIN pin senses the drain of a power MOSFET Output Motor Driver. The DRAIN voltage is an image of the current flowing through the power MOSFET. By limiting this voltage, the torque of the motor can be controlled.
TRIGGER	2	The TRIGGER input is an analog voltage control level used to fix the duty-cycle at the DRAIN Output. A voltage level here is determined by a potentiometer adjustment. The TRIGGER voltage level is compared with the triangle signal from the internal oscillator to produce a pulse-width modulated signal.
GND	3	Negative pole of the battery or system ground reference.
OSC	4	Oscillator output normally terminated in a charge/discharge capacitor. A constant current is flowing in and out to charge and discharge the external capacitor.
TORQUE	5	The TORQUE input is a reference level adjustment for torque control. The voltage reference is compared with DRAIN input. If $V_{DRAIN} > V_{TORQUE}$ , the GATE output pulse drive must be disabled.
DELAY	6	An external capacitor at the DELAY output is used to delay the torque control action. The external ca- pacitor at the DELAY pin will start to be charged if a MOSFET output over-current condition is detected. The purpose of the capacitor is to delay the disabling action of the signal GATE drive.
GATE	7	The GATE output drives the Gate of the Power MOSFET.
V <sub>DD</sub>	8	Positive pole of the battery or Power Supply Voltage, nominally 7.5V.



NOTE: The value chosen for the torque level set pot is dependent on the type of power MOSFET and motor characteristics. The TRIGGER is a combined SW/Speed Control function. Motor speed increases as the TRIGGER voltage decreases. Speed control range: 2.35V (Min) < V<sub>TRIGGER</sub> < 5.25V (Max)

FIGURE 2. TYPICAL OPERATING CIRCUIT SHOWING THE HIP9021IB AS AN N-CHANNEL MOSFET DRIVER IN A PORTABLE BATTERY ELECTRIC DRILL APPLICATION

### Functional Description

### Oscillator

The Oscillator triangle waveform is generated by the charge and discharge of a 1nF external capacitor connected to the OSC pin. The OSC terminal has a source and sink drive from a current mirror which delivers  $\pm 25\mu$ A. The charge and discharge of the external capacitor is controlled by 2 comparators which compare respectively V<sub>OSC</sub> with 2/3 V<sub>DD</sub> and V<sub>OSC</sub> with 1/3 V<sub>DD</sub>. The period of the triangle wave is nominally 200 $\mu$ s.

### Gate Driver

The TRIGGER input signal is compared from the triangle waveform of the oscillator to produce a square wave signal. The duty cycle of the GATE drive signal is increased as the TRIGGER input level increases. The output of the comparator is then NANDed with a GATE Control signal which can enable or disable the GATE output. The NAND gate output is buffered to deliver 18mA typical GATE drive current.

#### **Torque Effect**

The triangle signal, after going through a divider, is also compared with TRIGGER input level. This produces another square wave of the same period but with a duty-cycle that is smaller than the GATE by ~5%. This square wave is used to enable the comparison between DRAIN and TORQUE inputs while the MOSFET is conducting.

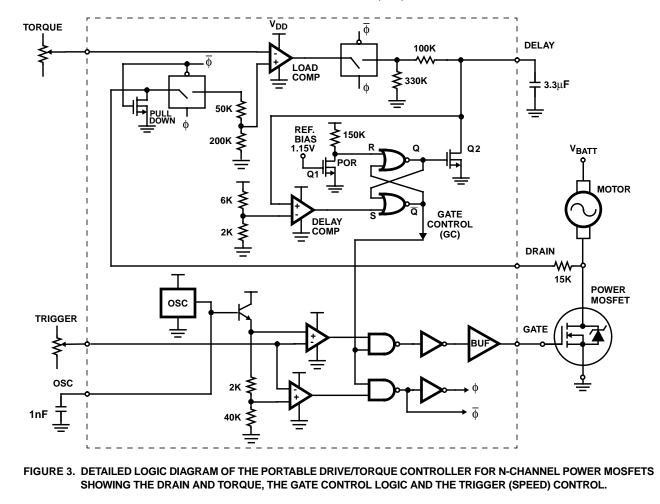
A torque effect condition exists when 80% of the DRAIN signal is higher than the TORQUE input level set voltage of the potentiometer. During this time, the external delay capacitor of  $3.3\mu$ F is charged through an internal 100K resistor. When the voltage at the DELAY pin reaches  $0.25 \times V_{DD}$ , the RS flip-flop is then set and the Gate Control (GC) signal shown in Figure 3 goes to low. The Output GATE drive signal is then disabled. This situation remains even if the voltage on the DELAY pin stays under  $0.25 \times V_{DD}$  for a sustained period of time.

At the same time, when the RS flip-flop is set, the external capacitor at the DELAY pin is discharged via the nMOS device, Q2 which is driven by the Q output of the flip-flop.

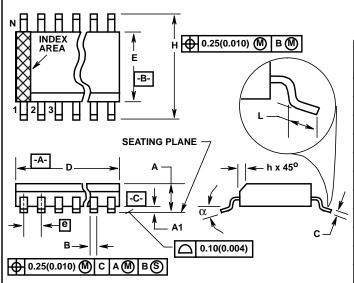
#### Power-On Reset (POR)

In reference to Figure 3, the power on of the chip will cause the reset of the RS Gate Control flip-flop when Q1 is switched low. As an initial condition, the Gate Control (GC) signal is reset high. Since power on is the only way to reset the RS flip-flop, a disabled GATE drive signal due to a torque effect condition requires a switched (trigger) reset.

The POR (power on reset) threshold requires that  $V_{DD}$  be less than 2V to initiate a reset. The POR circuit is based on the behavior of the voltage reference cell that produces a constant 1.15V (REF. BIAS) when  $V_{DD}$  is over 2V. When Q1 is forward biased, the Q1 drain voltage goes low to reset the input of the RS flip-flop.



## Small Outline Plastic Packages (SOIC)



#### **M8.15** (JEDEC MS-012-AA ISSUE C) 8 LEAD NARROW BODY SMALL OUTLINE PLASTIC PACKAGE

	INC	HES	MILLIN					
SYMBOL	MIN MAX MIN		MAX	NOTES				
А	0.0532	0.0688	1.35	1.75	-			
A1	0.0040	0.0098	0.10	0.25	-			
В	0.013	0.020	0.33	0.51	9			
С	0.0075	0.0098	0.19	0.25	-			
D	0.1890	0.1968	4.80	5.00	3			
E	0.1497	0.1574	3.80	4.00	4			
е	0.050	BSC	1.27 BSC		-			
Н	0.2284	0.2440	5.80	6.20	-			
h	0.0099	0.0196	0.25	0.50	5			
L	0.016	0.050	0.40	1.27	6			
Ν	8		8		7			
α	0 <sup>0</sup>	8 <sup>0</sup>	0 <sup>0</sup>	8 <sup>0</sup>	-			

#### NOTES:

- 1. Symbols are defined in the "MO Series Symbol List" in Section 2.2 of Publication Number 95.
- 2. Dimensioning and tolerancing per ANSI Y14.5M-1982.
- Dimension "D" does not include mold flash, protrusions or gate burrs. Mold flash, protrusion and gate burrs shall not exceed 0.15mm (0.006 inch) per side.
- Dimension "E" does not include interlead flash or protrusions. Interlead flash and protrusions shall not exceed 0.25mm (0.010 inch) per side.
- 5. The chamfer on the body is optional. If it is not present, a visual index feature must be located within the crosshatched area.
- 6. "L" is the length of terminal for soldering to a substrate.
- 7. "N" is the number of terminal positions.
- 8. Terminal numbers are shown for reference only.
- The lead width "B", as measured 0.36mm (0.014 inch) or greater above the seating plane, shall not exceed a maximum value of 0.61mm (0.024 inch).
- 10. Controlling dimension: MILLIMETER. Converted inch dimensions are not necessarily exact.

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